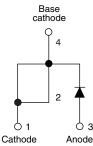


Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 4 A





PRODUCT SUMMARY							
Package	TO-220AC						
I _{F(AV)}	4 A						
V _R	600 V						
V _F at I _F	1.8 V						
t _{rr} typ.	17 ns						
T _J max.	150 °C						
Diode variation	Single die						

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA04TB60... is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 4 A continuous current, the VS-HFA04TB60... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RBM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA04TB60... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Cathode to anode voltage	V _R		600	V					
Maximum continuous forward current	١ _F	T _C = 100 °C	4						
Single pulse forward current	I _{FSM}		25	А					
Maximum repetitive forward current	I _{FRM}		16						
Maximum power dissipation	р	T _C = 25 °C	25	W					
Maximum power dissipation	P _D	T _C = 100 °C	10	vv					
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C					

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RoHS

COMPLIANT

HALOGEN

FREE



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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS			
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-				
		I _F = 4.0 A		-	1.5	1.8				
Maximum forward voltage	V_{FM}	I _F = 8.0 A	See fig. 1	-	1.8	2.2				
		I _F = 4.0 A, T _J = 125 °C		-	1.4	1.7				
Maximum reverse		$V_{R} = V_{R}$ rated	See fig. 0	-	0.17	3.0				
leakage current	I _{RM}	$T_J = 125 \ ^\circ C, V_R = 0.8 \ x \ V_R$ rated	See fig. 2	-	44	300	μA			
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	4.0	8.0	pF			
Series inductance	L _S	Measured lead to lead 5 mm from body	package	-	8.0	-	nH			

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time See fig. 5, 6 and 16	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$) A/µs, V _R = 30 V	-	17	-				
	t _{rr1}	T _J = 25 °C		-	28	42	ns			
	t _{rr2}	T _J = 125 °C		-	38	57				
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	2.9	5.2	А			
See fig. 7 and 8	I _{RRM2}	T _J = 125 °C	$I_F = 4 A$	-	3.7	6.7				
Reverse recovery charge	Q _{rr1}	T _J = 25 °C	dl _F /dt = 200 A/µs V _B = 200 V	-	40	60	nC			
See fig. 9 and 10	Q _{rr2}	T _J = 125 °C	VR - 200 V	-	70	105	no			
Peak rate of fall of recovery current during t _h	dl _{(rec)M} /dt1	T _J = 25 °C		-	280	-	۸/ue			
See fig. 11 and 12	dl _{(rec)M} /dt2	T _J = 125 °C		-	235	-	A/µs			

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	MIN.	TYP.	MAX.	UNITS					
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C			
Thermal resistance, junction to case	R _{thJC}		-	-	5.0				
Thermal resistance, junction to ambient	R _{thA}	Typical socket mount	-	-	80	K/W			
Thermal resistance, case to heatsink	R _{thS}	Mounting surface, flat, smooth and greased	-	0.5	-				
Weight			-	2.0	-	g			
weight			-	0.07	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Marking device		Case style TO-220AC	HFA04TB60						

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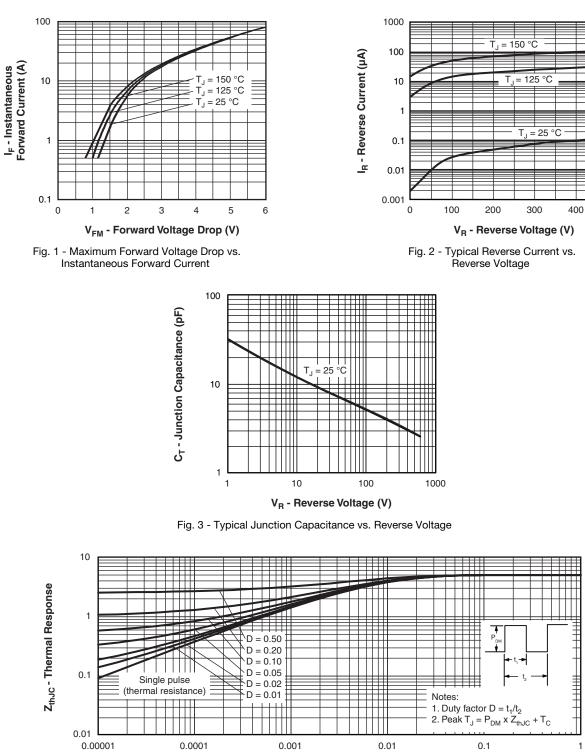
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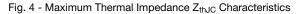


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500



t₁ - Rectangular Pulse Duration (s)



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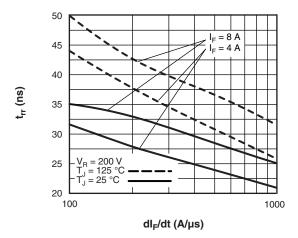


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

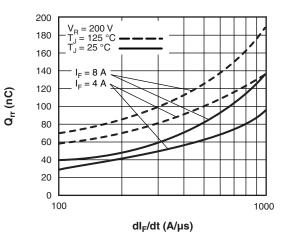


Fig. 7 - Typical Stored Charge vs. dl_F/dt

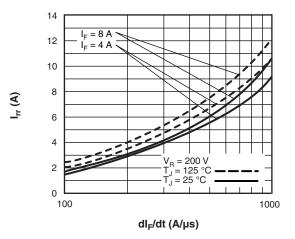


Fig. 6 - Typical Recovery Current vs. dl_F/dt

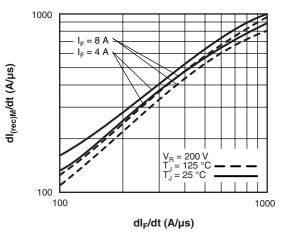


Fig. 8 - Typical dI_{(rec)M}/dt vs. dI_F/dt



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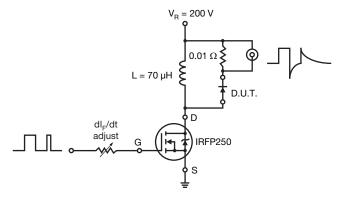


Fig. 9 - Reverse Recovery Parameter Test Circuit

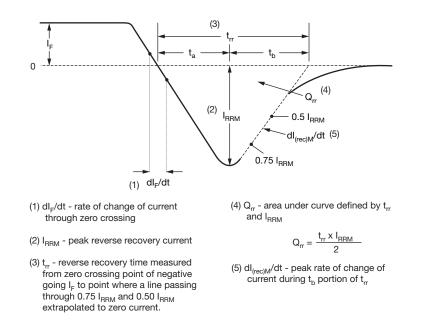


Fig. 10 - Reverse Recovery Waveform and Definitions



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ORDERING INFORMATION TABLE

1 2 3 4 5 6 7 1 - Vishay Semiconductors product 2 - HEXFRED [®] family 3 - Electron irradiated 4 - Current rating (04 = 4 A) 5 - Package: TB = TO-220AC 6 - Voltage rating (60 = 600 V) 7 - Environmental digit: PbF = Lead (Pb)-free and RoHS compliant	Device code	VS-	HF	Α	04	тв	60	PbF
 HEXFRED[®] family Electron irradiated Current rating (04 = 4 A) Package: TB = TO-220AC Voltage rating (60 = 600 V) Environmental digit: 			2	3	4	5	6	7
-N3 = Halogen-free, RoHS compliant and		2 - 3 - 4 - 5 -	HE: Electric Pace TB Voltric Env	KFRED [®] ctron irra rent rati kage: = TO-22 age rati ironmer = Lead	[®] family adiated ng (04 = 20AC ng (60 = ntal digit I (Pb)-fre	= 4 A) = 600 V) : ee and F	RoHS cr	

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-HFA04TB60PbF	50	1000	Antistatic plastic tube						
VS-HFA04TB60-N3	50	1000	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95221					
	TO-220ACPbF	www.vishay.com/doc?95224					
Part marking information	TO-220AC-N3	www.vishay.com/doc?95068					



Vishay Semiconductors

TO-220AC

plane

DIMENSIONS in millimeters and inches









Diodes 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

⊕ 0.015 **()** BA()

SYMBOL	MILLIN	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDOL	MIN.	MAX.	MIN.	MAX.	NULES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1
- ⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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